INTEGRATED CIRCUITS

DATA SHEET

74LV368

Hex buffer/line driver; inverting (3-State)

Product specification Supersedes data of 1997 Apr 07 IC24 Data Handbook





Hex buffer/line driver; inverting (3-State)

74LV368

FEATURES

- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between V_{CC} = 2.7V and V_{CC} = 3.6V
- Typical V_{OLP} (output ground bounce) < 0.8V @ V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2V @ V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Inverting outputs
- Output capability: bus driver
- I_{CC} category: SSI

DESCRIPTION

The 74LV368 a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT368.

The 74LV368 is a hex inverting buffer/line driver with 3-state outputs. The 3-state outputs (nY) are controlled by the output enable inputs 10E and 20E. A HIGH on n0E causes the outputs to assume a high impedance OFF-state.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA to nŸ	$C_L = 15pF$ $V_{CC} = 3.3V$	9.0	ns
C _I	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per buffer	Notes 1, 2	30	pF

- 1 C_{PD} is used to determine the dynamic power dissipation (P_D in μW) P_D is used to determine the dynamic power dissipation (P_D in properties of the properties of the

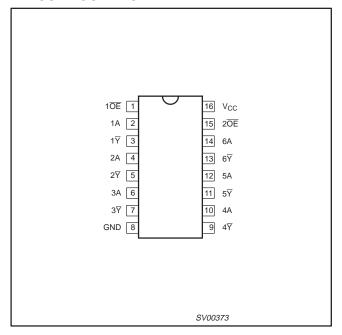
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
16-Pin Plastic DIL	-40°C to +125°C	74LV368 N	74LV368 N	SOT38-4
16-Pin Plastic SO	–40°C to +125°C	74LV368 D	74LV368 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV368 DB	74LV368 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV368 PW	74LV368PW DH	SOT403-1

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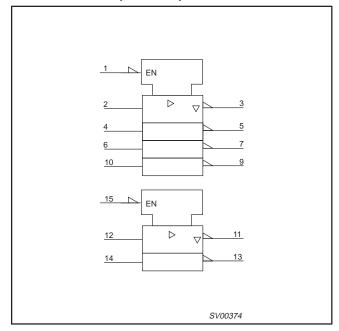
PIN CONFIGURATION



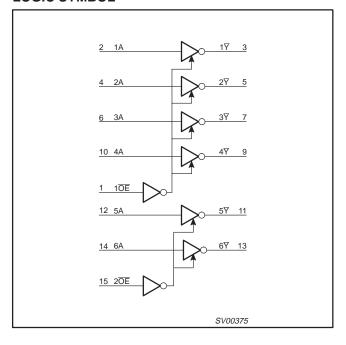
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 15	1 OE to 2 OE	Output enable inputs (active LOW)
2, 4, 6, 10, 12, 14	1A to 6A	Data inputs
3, 5, 7, 9, 11, 13	1Ÿ to 6Ÿ	Bus outputs
8	GND	Ground (0V)
16	V _{CC}	Positive supply voltage

LOGIC SYMBOL (IEEE/IEC)



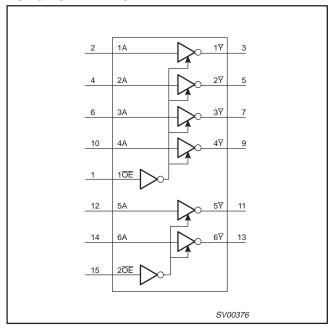
LOGIC SYMBOL



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FUNCTIONAL DIAGRAM



FUNCTION TABLE

INP	OUTPUT	
nOE	nA	nΫ
L	L	Н
L	Н	L
Н	X	Z

NOTES:

H = HIGH voltage level

L = LOW voltage level

X = Don't care

Z = High impedance OFF-state

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CC}	DC supply voltage	See Note ¹	1.0	3.3	3.6	V
VI	Input voltage		0	-	V _{CC}	V
Vo	Output voltage		0	_	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.0V \text{ to } 2.0V$ $V_{CC} = 2.0V \text{ to } 2.7V$ $V_{CC} = 2.7V \text{ to } 3.6V$	- - -	- - -	500 200 100	ns/V

NOTES:

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134); Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
±l _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5V$	20	mA
±I _{OK}	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5V$	50	mA
±I _O	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with –bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package -plastic DIL -plastic mini-pack (SO) -plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

¹ The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 3.6V.

¹ Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

² The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8	5°C	-40°C to	+125°C	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	1
		V _{CC} = 1.2V	0.9			0.9		
V_{IH}	HIGH level Input voltage	V _{CC} = 2.0V	1.4			1.4		V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	2.0			2.0		
	LOW/Invaliance	V _{CC} = 1.2V			0.3		0.3	
V_{IL}	LOW level Input voltage	V _{CC} = 2.0V			0.6		0.6	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}$			0.8		0.8	
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$		1.2				
V _{OH}	HIGH level output	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	1.8	2.0		1.8		
VOH	voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.5	2.7		2.5		7 °
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.8	3.0		2.8		1
V _{OH}	HIGH level output voltage; BUS driver outputs	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 8\text{mA}$	2.40	2.82		2.20		V
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0				
\/	LOW level output	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2] ,
V_{OL}	voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 100 \mu A$		0	0.2		0.2	7 °
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	1
V _{OL}	LOW level output voltage; BUS driver outputs	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 8\text{mA}$		0.20	0.40		0.50	V
II	Input leakage current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND			1.0		1.0	μА
I _{OZ}	3-State output OFF-state current	$V_{CC} = 3.6V$; $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND			5		10	μА
Icc	Quiescent supply current; MSI	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		160	μА
Δl _{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$			500		850	μА

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NOTE:

¹ All typical values are measured at $T_{amb} = 25^{\circ}C$.

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AC CHARACTERISTICS

GND = 0V; t_r = t_f = 2.5ns; C_L = 50pF; R_L = 1K Ω

SYMBOL	PARAMETER	WAVEFORM	CONDITION		LIMITS 40 to +85 °	С		ITS ⊦125 °C	UNIT
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX	
Propagation delay			1.2	_	55	_	_	_	
	Figures, 1, 3	2.0	_	19	36	-	44	ns	
I IPZL/IPLH	t _{PZL} /t _{PLH} nA, to nY	rigules, i, s	2.7	_	14	26	-	33	115
		3.0 to 3.6	_	10 ²	21	_	26		
		Figures, 2, 3	1.2	_	75	_	-	_	
t _{PZH} /t _{PZL}	3-State output enable time		2.0	_	26	49	_	60	ns
IPZH/IPZL	nOE to nY	1 igules, 2, 3	2.7	_	19	36	_	44	113
			3.0 to 3.6	-	14 ²	29	-	35	
			1.2	_	90	_	-	-	
touztouz	3-State output disable time	Figures 2.3	2.0	_	32	59	_	70	ns
t _{PHZ} /t _{PLZ}	nOE to nY	Figures, 2, 3	2.7	_	24	44	_	52	115
			3.0 to 3.6	_	19 ²	36	-	42	

NOTE:

1 Unless otherwise stated, all typical values are at $T_{amb} = 25$ °C.

2 Typical value measured at $V_{CC} = 3.3V$.

AC WAVEFORMS

 V_{M} = 1.5V at $V_{CC} \ge 2.7V$

 $V_{M} = 0.5V * V_{CC}$ at $V_{CC} < 2.7V$

 $\mbox{V}_{\mbox{OL}}$ and $\mbox{V}_{\mbox{OH}}$ are the typical output voltage drop that occur with the output load.

 $V_X = V_{OL} + 0.3V$ at $V_{CC} \ge 2.7V$

 $V_X = V_{OL} + 0.1 * V_{CC}$ at $V_{CC} < 2.7V$

 $V_Y = V_{OH} - 0.3V$ at $V_{CC} \ge 2.7V$

 $V_Y = V_{OH} - 0.1V_{CC}$ at $V_{CC} < 2.7V$

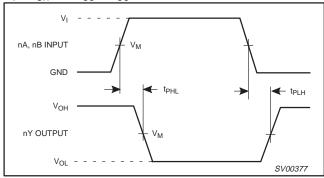


Figure 1.Input (nA) to output $(n\overline{Y})$ propagation delay

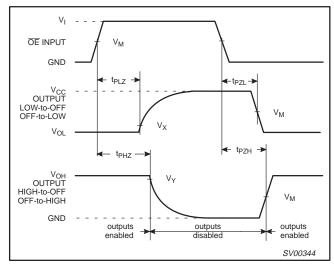


Figure 2. 3-State enable and disable times

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TEST CIRCUIT

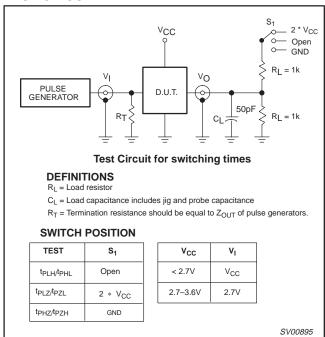


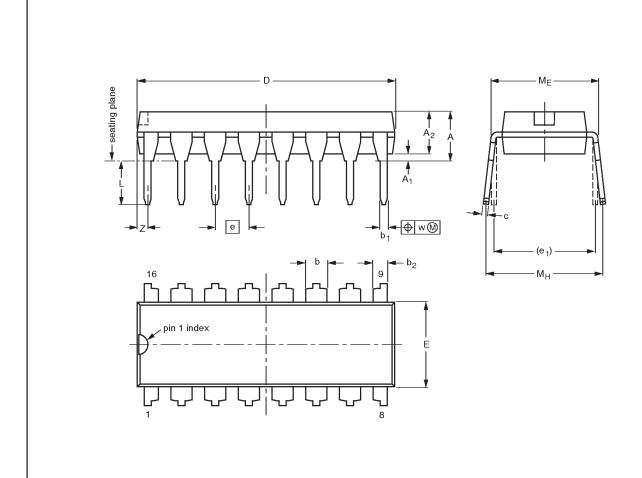
Figure 3. Load circuitry for switching times

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DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UI	NIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	C	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
m	nm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inc	hes	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

scale

10 mm

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE	
SOT38-4						92-11-17 95-01-14

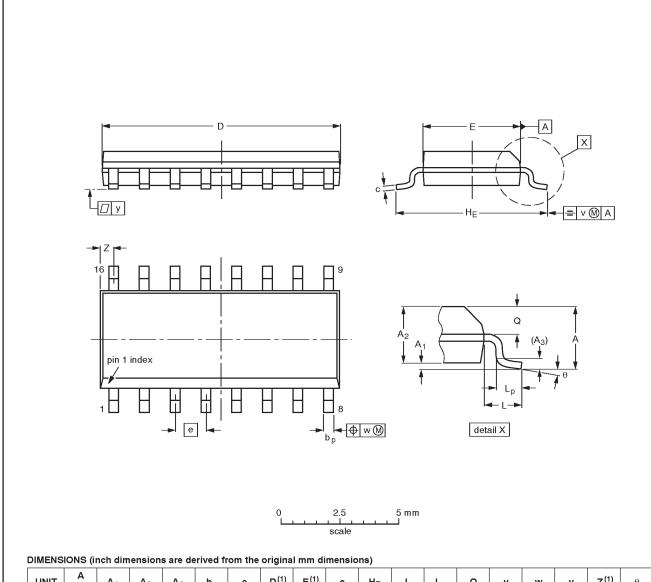
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SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039		0.01		0.0098 0.0075	0.39 0.38	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT109-1	076E07S	MS-012AC			91-08-13 95-01-23	

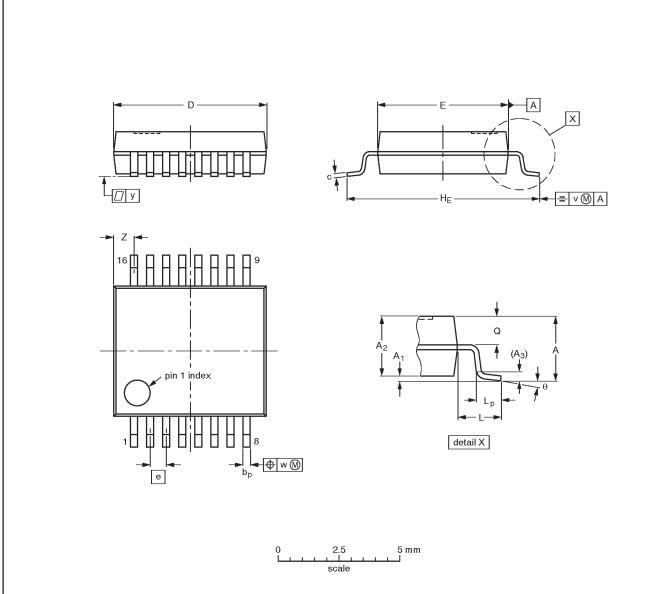
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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	рb	c	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT338-1		MO-150AC				94-01-14 95-02-04	

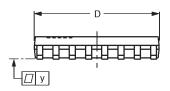
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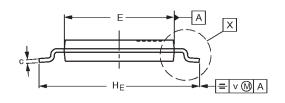
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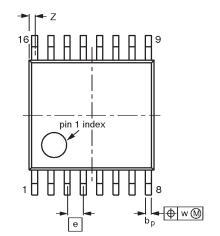
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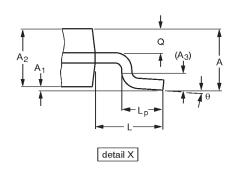
TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

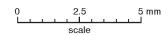
SOT403-1











DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	c	D ⁽¹⁾	E ⁽²⁾	Φ	HE	L	Lp	ø	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				-94-07-12 95-04-04	

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DEFINITIONS						
Data Sheet Identification	Product Status	Definition				
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.				
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.				
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.				

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print code Date of release: 05-96

Document order number: 9397-750-04446

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